Mott-Hubbard and Anderson Metal-Insulator Transitions

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March 05th, 2004



Main goal:

Some random events are better classified by geometric average

Main result:

Zero-temperature phase diagram of the disordered Hubbard model at half filling



Collaboration:

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Plan of the talk:

- 1. Introduction
 - Mott-Hubbard and Anderson metal-insulator transitions (MIT)
 - Description of Anderson localization
 - Widely distributed random quantities
 - Arithmetic vs. geometric means
- 2. Modification within DMFT to include Anderson localization
- 3. Phase diagram and MITs in details
- 4. Conclusions

Insulators:

$$\sigma_{\alpha,\beta}^{DC}(T=0) = \lim_{T \to 0^+} \lim_{\omega \to 0} \lim_{|\mathbf{q}| \to 0} \Re[\sigma_{\alpha,\beta}(\mathbf{q},\omega)] = 0$$

There is a gap $\Delta(\lambda) > 0$ in the single – particle spectrum

- robust gap exists for all temperature
- soft gap vanishes for $T > T_c$
- quantum phase transition competition between E_{kin} and E_{pot}
- thermodynamic phase transitions competition between U and S
- single particle: due to electron ion interactions
 - Bloch Wilson (band) insulators
 - Peierls (lattice deformation) insulators
 - Anderson (lattice randomness) insulators (!)
- many particle: due to electron electron interactions
 - Slater (SDW) insulators
 - Mott Hubbard (PM) insulators (!!)
 - Mott Heisenberg (localized AF) insulators

Mott-Hubbard metal-insulator transition at





$$U \gg |t_{ij}|$$
, $\Delta \mathbf{r} = 0$

Antiferromagnetic Mott insulator



typical intermediate coupling problem $U_c \approx |t_{ij}|$

Hubbard model to capture right physics



$$H = \sum_{i\sigma} \epsilon_0 n_{i\sigma} + \sum_{ij\sigma} t_{ij} \ a_{i\sigma}^{\dagger} a_{j\sigma} + U \sum_i n_{i\uparrow} n_{i\downarrow}$$

- long history, many contradictions
- exactly solvable in d = 1
- exactly solvable in $d = \infty$ (DMFT)
- how to approximate in $1 < d < \infty$?

Physical picture, n = 1



spin flip on central site

dynamical processes with spin-flips inject states into correlation gap giving a quasiparticle resonance

T=0 Mott transition according to DMFT Kotliar et al. 92-96, Bulla, 99



Mott transition at T > 0Kotliar et al. 92-96, Bulla et al. 01, also Spalek 87



 1^{st} -order transition



Anderson localization:

propagation of waves in a randomly inhomogeneous medium



random conservative linear wave equation

$$\frac{\partial^2 w}{\partial t^2} = c(x)^2 \frac{\partial^2 w}{\partial x^2}$$

$$i\frac{\partial w}{\partial t} = -\frac{\partial^2 w}{\partial x^2} + \nu(x)w$$

diffusive motion, memory of $\vec{V}(0)$ lost, "random walk" over long distances, friction imposed by averaging

Anderson 1958: (no averaging) – strong scattering forms "standing" waves, sloshing back and forth in a bounded region of space

Localization is a destruction of coherent superposition of spatially separated states

Anderson model:

$$H = \sum_{i\sigma} \epsilon_i n_{i\sigma} + \sum_{ij\sigma} t_{ij} a_{i\sigma}^{\dagger} a_{j\sigma}$$

Probability distribution function

$$\mathcal{P}(\boldsymbol{\epsilon_i}) = \frac{1}{\Delta} \Theta\left(\frac{\Delta}{2} - |\boldsymbol{\epsilon_i}|\right)$$



Anderson MIT - cont.:

Returning probability $P_{j \to j}(t \to \infty; V \to \infty)$?



 $P_{j \to j}(t \to \infty; V \to \infty) = 0$ for extended states

 $P_{j \to j}(t \to \infty; V \to \infty) > 0$ for localized states

Anderson MIT - cont.:

According to one-parameter scaling theory [g = g(L)] (noninteracting system)

- If dim = 1 or 2 all states are localized
- If dim=3 there is a critical disorder above which the states are localized



Characterization of Anderson localization:

- Decaying of wavefunction $|\Psi_n(r_i)| \sim e^{-|r-r_i|/\xi(E_n)}$
 - metal $\xi \to \infty$
 - insulator $\xi < \infty$
- Inverse participation ratio P^{-1} [inverse number of sites that contribute to $\Psi_n(r_i)$]
 - metal $P^{-1} \sim 1/N$
 - insulator $P^{-1} \sim \text{const}$

Characterization of Anderson localization:

- Conductance G
 - metal G > 0
 - insulator G = 0
- Local Density of States (LDOS)

$$\rho_i(E) = \sum_{n=1}^N |\Psi_n(r_i)|^2 \delta(E - E_n)$$

Local DOS in DMFT

Heuristic arguments:

$$P_{j \to j}(t) = |G_j(t)|^2$$

$$G_j(t) \sim e^{i(\epsilon_j + \Sigma'_j)t - |\Sigma''_j|t} \sim e^{-\frac{t}{\tau_{\text{esc}}}}$$

Fermi Golden Rule



Statistics of LDOS:

 $\rho_j(E)$ is different at different R_j ! Random quantity!

Statistical description $P[\rho_j(E)]!$

Exact diagonalization – Schubert et al. cond-mat/0309015



Typical escape rate is determined by the typical LDOS

Anderson MIT - cont.:

Near Anderson localization typical LDOS is approximated by geometrical mean



Theorem (F.Wegner 1981):

$$\rho(E)_{av} = \langle \rho_i(E) \rangle > 0$$

within a band for any finite Δ

Schubert et al. cond-mat/0309015

Anderson MIT - cont.:

Why should it work at all?

$$\rho_{geom}(E) = e^{\langle \ln \rho_i(E) \rangle} = e^{\frac{1}{\Delta} \sum_{i=1}^N \ln \rho_i(E)} = \prod_{i=1}^N \rho_i(E)^{\frac{1}{\Delta}}$$

$$\exists \ \rho_i(E) = 0 \Longrightarrow \rho_{geom}(E) = 0$$

Dynamical mean-field theory for U

Kotliar et al., Vollhardt et al.

Lattice problem of interacting particles is mapped onto a single impurity (single atom) coupled to the molecular bath



Molecular (Weiss) function $\mathcal{G}(\omega)$ is a dynamical quantity, determined self-consistently

DMFT with Anderson MIT:

after idea from: Dobrosavljevic et al., Europhys. Lett. 62, 76 (2003)

$$H^{\text{SIAM}} = \sum_{\sigma} (\epsilon_{i} - \mu) a_{i\sigma}^{\dagger} a_{i\sigma} + U n_{i\uparrow} n_{i\downarrow} + \sum_{\mathbf{k}\sigma} V_{\mathbf{k}} a_{i\sigma}^{\dagger} c_{\mathbf{k}\sigma} + hc + \sum_{\mathbf{k}\sigma} \epsilon_{\mathbf{k}} c_{\mathbf{k}\sigma}^{\dagger} c_{\mathbf{k}\sigma}$$
$$G(\omega, \epsilon_{i}) \rightarrow \rho_{i}(\omega) = -\frac{1}{\pi} \text{Im} G(\omega, \epsilon_{i})$$
$$\rho_{g}(\omega) = e^{\langle \ln \rho_{i}(\omega) \rangle}; \quad G(\omega) = \int d\omega' \frac{\rho_{g}(\omega)}{\omega - \omega'}$$
$$G^{-1}(\omega) = \omega - \eta(\omega) - \Sigma(\omega), \quad \eta(\omega) = \sum_{\mathbf{k}} \frac{|V_{\mathbf{k}}|^{2}}{\omega - \epsilon_{\mathbf{k}}}$$
$$G(\omega) = \int d\epsilon \frac{N_{0}(\epsilon)}{\omega - \epsilon - \Sigma(\omega)}$$

Phase diagram for disordered Hubbard model:

$$N_0(\epsilon) = \frac{2}{\pi D} \sqrt{D^2 - \epsilon^2}; \quad \eta(\omega) = \frac{D^2}{4} G(\omega)$$

T = 0, n = 1, W = 2D = 1



Mott-Hubbard transition in disordered Hubbard model:



* Similar conclusions with $\langle \rho_j \rangle$ schme

Spectral functions in disordered Hubbard model:

U/W=1.75

U/W=1.25





- * Redistribution of spectral weight
- * Reentrant Mott-Hubbard MIT
- * Anderson MIT $\rho_{geom}(\omega) \rightarrow 0$

Anderson transition in Hubbard model:





* Two insulators: Mott and Anderson

* Adiabatic continuity

 $(U > 0, \Delta = 0) \rightarrow (U = 0, \Delta > 0)$

Conclusions:

- Geometrical means used to study Anderson MIT in correlated electron system within DMFT
- Complete phase diagram
- Hysteresis and crossover in Mott-Hubbard MIT
- Nonmonotonic behavior of $\Delta_c(U)$ at Anderson MIT
- Two insulators connected adiabatically

Log-normal distribution - tutorial:

$$f(x) = \frac{1}{\sqrt{2\pi\sigma^2}} \frac{1}{x} e^{-\frac{(\ln x - \mu)^2}{2\sigma^2}}$$

- It has both long tail and all moments
- Typical value $x_{typ} = e^{\mu \sigma^2}$

• Median
$$x^{med} = e^{\mu}$$



Log-normal distribution - cont.:

Log-normal distribution serves as a prototype distribution which is characterized by infinitely many moments

F. Galton 1879; D. McAlister 1879

How to get log-normal?

•
$$x = e^y$$

• $x_n = \prod_{i=1}^n y_i$ with CLT

Applications: astrophysics, physics (glass, polymers, networks), economy, sociology, biology, geology, etc.